
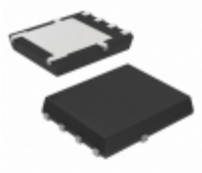
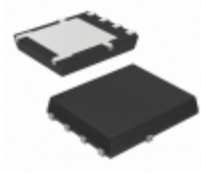
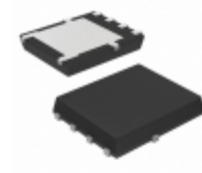
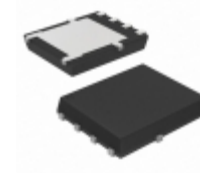
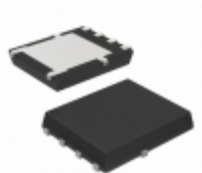
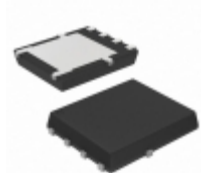
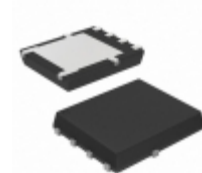
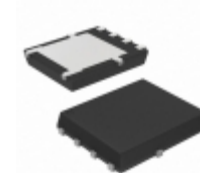
	<h2>NTMFS4121NT1G</h2>
	<p>Hersteller-Teilenummer: NTMFS4121NT1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 11A SO8FL</p> <p>Datenblätter:  NTMFS4121NT1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 3597 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTMFS4121NT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 11A SO8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	3597 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN, 5 Leads
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Verlustleistung (max)	900mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	11A (Ta)
Rds On (Max) @ Id, Vgs	5.25 mOhm @ 24A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	40nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	2700pF @ 24V
Verpackung	Tape & Reel (TR)

NTMFS4121NT1G ist neu im Original, Suche NTMFS4121NT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTMFS4121NT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTMFS4121NT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTMFS4121NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 11A SO8FL</p>	 <p>NTMFS4120NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 11A SO8FL</p>	 <p>NTMFS4701NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 7.7A SO8FL</p>	 <p>NTMFS4119NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 11A SO8FL</p>
 <p>NTMFS4122NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 9.1A SO8FL</p>	 <p>NTMFS4701NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 7.7A SO8FL</p>	 <p>NTMFS4120NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 11A SO8FL</p>	 <p>NTMFS4119NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 11A SO8FL</p>

heiße Teile

Mehr

NTMD6N02	NTMD6N02DR2G	NTMD6N02R2G	NTMD6N03	NTMD6N03DR2G
NTMD6N03R2	NTMD6N03R2G	NTMD6N04	NTMD6N04R2G	NTMD6P02
NTMD6P02R2	NTMD6P02R2G	NTMD6P02R2G.	NTMD6P02R2SG	NTMFD4901NF1G
NTMFD4901NFT1G	NTMFD4902NF1G	NTMFD4902NFT1G	NTMFD4C85NT1G	NTMFD4C85NTG
NTMFD4H089NFT1G	NTMFS4108NT1G	NTMFS4108NT3G	NTMFS4119NT3G	NTMFS4120NT1G
NTMFS4701NT1G	NTMFS4707NT1G	NTMFS4708NT1G	NTMFS4709NT1G	NTMFS4709NT3G
NTMFS4744NT1G	NTMFS4821NT1G	NTMFS4823NT1G	NTMFS4833NT1G	NTMFS4834N
NTMFS4834NT1G	NTMFS4835N	NTMFS4835NT1G	NTMFS4837NHT1G	NTMFS4837NHT3G
NTMFS4837NT1G	NTMFS4839NHT1G	NTMFS4841NHT1G	NTMFS4841NHT3G	NTMFS4841NT1G
NTMFS4845NT1G	NTMFS4846	NTMFS4846NT1G	NTMFS4847N	NTMFS4847NAT1G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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